EE434 ASIC & Digital Systems

Partha Pande School of EECS Washington State University pande@eecs.wsu.edu

Spring 2015 Dae Hyun Kim daehyun@eecs.wsu.edu

Lecture 1

Course Overview & Introduction to VLSI

Theme of the Course

- How to design and analyze a complex application-specific integrated circuit (ASIC)
- At the end of this semester, you will be able to
 - Understand how a VLSI chip works
 - Design complex digital VLSI circuits and systems
 - Understand basic theories behind VLSI
 - Analyze VLSI circuits and systems

Target of the Course

- We will follow a bottom-up approach
- We are not going to discuss much about devices
- Rather we will learn more system level issues, both design and analysis
- But to appreciate the problems related to the design of a big digital system we need to learn about circuits and gates

Broad Categories

- Three broad topics
 - Circuit Design Styles
 - CMOS and other circuit families, delay, power, clock, interconnects
 - Implementation Methods
 - Custom & Semicustom design
 - Standard cell-based design
 - FPGAs
 - Physical design of CMOS VLSI circuits and systems
 - Verilog
 - Design
 - Analysis
 - Optimization

Schedule

- Week 1 (1/12,14,16): Introduction to VLSI
- Week 2 (1/21,23): CMOS transistors, switches, gates
- Week 3 (1/26,28,30): CMOS inverter, combinational logic
- Week 4 (2/2,4,6): CMOS design styles, sequential logic
- Week 5 (2/9,11,13): Characterization and performance estimation
- Week 6 (2/18,20): Characterization and performance estimation (continued)
- Week 7 (2/23,25,27): Midterm 1, layout, simulation, optimization
- Week 8 (3/2,4,6): Interconnects
- Week 9 (3/9,11,13): Timing analysis
- Week 10: Break
- Week 11 (3/23,25,27): Memory
- Week 12 (3/30,4/1,3): Design methodologies (Full-custom, FPGA, ...)
- Week 13 (4/6,8,10): Midterm 2, Verilog, synthesis, timing and power analysis
- Week 14 (4/13,15,17): Verilog, datapath design, synthesis
- Week 15 (4/20,22,24): Physical design, arithmetic units
- Week 16 (4/27,29,5/1): Project presentation

References

- FPGA-BASED System Design by Wayne Wolf, Prentice Hall, 2004, ISBN 0-13-142461-0
- Analysis and Design of Digital Integrated Circuits by Hodges, Jackson, and Saleh, 3/E, 2003, McGraw Hill, ISBN 0072283653
- CMOS VLSI Design: A Circuits and Systems Perspective by Weste and Harris, 4/E, 2010, Addison-Wesley, ISBN 0321547748
- Digital Integrated Circuits by Rabaey, Chandrakasan, and Nikolic, 2E, 2003, Prentice Hall, ISBN 0130909963
- Introduction to VLSI Circuits and Systems by Uyemura, 1E, 2001, Wiley, ISBN 0471127043
- CMOS Logic Circuit Design by Uyemura, 1999, Springer, ISBN 0387781641
- Application-Specific Integrated Circuits by Smith, 1997, Addison-Wesley, ISBN 0201500221
- Extra reading materials will be supplied in the class

Assignments

- There will be several homework assignments
 - Due dates will be mentioned when handed out
 - Late submissions are not allowed
- Lab and HW are very important parts of this course
 - Lab assignments will involve Verilog RTL coding
 - No worries! You will learn Verilog step by step.
 - You will learn Synopsys and Cadence tools
 - No worries! Detailed tutorials will be provided.
 - EME 205 is the lab for this course
 - You will be allowed to work any time in the lab
 - TA will be available only in fixed hours



- Important announcements will be posted in the course website
 - www.eecs.wsu.edu/~ee434

Discrete Components vs. VLSI

	Discrete components	Integrated circuits
# transistors	10 ²	10 ⁹



What is an ASIC?

- Application Specific Integrated Circuits
- Integrated Circuits
 - All components, passive and active are integrated on a single semiconductor substrate
 - Higher speed
 - Lower power
 - Physically smaller
- Integration reduces manufacturing cost

Yield

• Defects



Yield



Yield

• Need for larger wafer size



Technology Scaling

- Integration of more transistors in the same area
 - Higher yield
 - Lower cost
 - More functionality
 - Lower power consumption
- Parasitic RC?





MOS Transistor Scaling

(1974 to present)



Ideal Technology Scaling (constant field)

<u>Quantity</u>	Before Scaling	After Scaling
Channel Length	L	L' = L * s
Channel Width	W	W' = W * s
Gate Oxide thickness	t _{ox}	$t'_{ox} = t_{ox} * s$
Junction depth	Xj	$x'_{j} = x_{j} * s$
Power Supply	V _{dd}	V _{dd} ' = Vdd * s
Threshold Voltage	V _{th}	$V'_{th} = V_{th} * s$
Doping Density, p n+	N _A N _D	N _A ' = N _A / s N _D ' = N _D / s

Technology Scaling (Device)

- Area: $W \cdot L \rightarrow s^2 W \cdot L$
- Capacitance - $W \cdot L \cdot c_{ox} = (W \cdot L) \cdot \frac{\varepsilon_{ox}}{t_{ox}} \rightarrow (s^2 W L) \cdot \frac{\varepsilon_{ox}}{s \cdot t_{ox}} = (sWL) \cdot \frac{\varepsilon_{ox}}{t_{ox}}$
- Transistor delay

$$- t_p \propto \frac{C_L V_{DD}}{k(V_{DD} - V_T)^2} \rightarrow \frac{(sC_L)(sV_{DD})}{\left(\mu \cdot c_{ox} \cdot \frac{W}{L}\right)(sV_{DD} - sV_T)^2} = \frac{(sC_L)(sV_{DD})}{(\mu \cdot \frac{\varepsilon_{ox}}{s \cdot t_{ox}} \cdot \frac{sW}{sL})(sV_{DD} - sV_T)^2} = \frac{s\left(\frac{C_L V_{DD}}{k(V_{DD} - V_T)^2}\right)}{(m \cdot \frac{\varepsilon_{ox}}{s \cdot t_{ox}} \cdot \frac{sW}{sL})(sV_{DD} - sV_T)^2}$$

Power consumption

$$- P \propto \alpha f C_L V_{DD}^2 \rightarrow \alpha(\frac{f}{s})(sC_L)(s^2 V_{DD}^2) = s^2(\alpha f C_L V_{DD})$$

• Power / Area = 1

ox

Technology Scaling (Interconnect)

- Width: $W \rightarrow sW$
- Thickness: $t \rightarrow st$
- Spacing: $d \rightarrow sd$
- Length: $l \rightarrow sl$



• Resistance: $\rho \frac{l}{tw} = \rho \frac{sl}{(st)(sw)} = \frac{1}{s} \rho \frac{l}{tw}$

• Capacitance:
$$\varepsilon \frac{tl}{d} = \varepsilon \frac{(st)(sl)}{sd} = \mathbf{s}\varepsilon \frac{tl}{d}$$

• Interconnect delay: $\propto RC = 1$

Technology Scaling



Source: SIA Roadmap

Moore's Law



Number of transistors per chip would double every 18 months.

MPU Trends - Moore's Law



More MPU Trends



MPU Clock Frequency Trend



What about power in the future?



Recent Trends

- 1.5GHz Itanium chip (Intel), 410M tx, 374mm², 130W@1.3V
- 1.1 GHz POWER4 (IBM), 170M tx, 115W@1.5V
 - if these trends continue, power will become unmanageable
- 150Mhz Sony Graphics Processor, 7.5M tx (logic) + 280M tx (memory) = 288M tx, 400mm² 10W@1.8V
 - if trend continues, most designs in the future will have a high percentage of memory
- Single-chip Bluetooth transceiver (Alcatel), 400mm², 150mW@2.5V
 - required 30 designers over 2.5 years (75 person-years)
 - if trend continues, it will be difficult to integrate larger systems on a single chip in a reasonable time
- Intel's 80-core chip
 - In 65-nm technology with 80 single-precision, floating point cores delivers performance in excess of a teraflops while consuming less than 100 w
 - Tilera Corporation (Dedicated Multi-core company)
 - Multi-core design will dominate

Technology Nodes 1999-2019



Two year cycle between nodes until 2001, then 3 year cycle begins.

Intel Pentium (IV) microprocessor



Design Abstraction Levels



ASIC Realization Process

